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[DMP3030SN-7](#)

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sales@integrated-circuit.com



P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

DMP3030SN

NEW PRODUCT

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- **Lead Free By Design/RoHS Compliant (Note 2)**
- **ESD Protected Gate**
- **"Green" Device (Note 4)**
- **Qualified to AEC-Q101 standards for High Reliability**

Mechanical Data

- Case: SC59
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.014 grams (approximate)

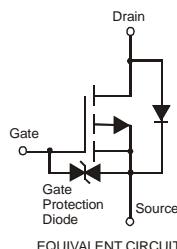


ESD protected

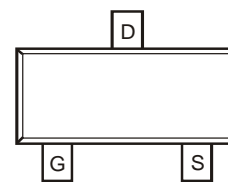


TOP VIEW

SC59



EQUIVALENT CIRCUIT



Internal Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current (Note 1) Steady State	I _D	-0.7	A
Pulsed Drain Current (Note 3)	I _{DM}	-2.8	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P _d	500	mW
Thermal Resistance, Junction to Ambient	R _{θJA}	250	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-10	μA	V _{DS} = -30V, V _{GS} = 0V
Gate-Body Leakage	I _{GSS}	—	—	±10	μA	V _{GS} = ±20V, V _{DS} = 0V
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	-1.0	—	-3.0	V	V _{DS} = -10V, I _D = -1.0mA
Static Drain-Source On-Resistance	R _{DS (ON)}	—	0.20 0.35	0.25 0.45	Ω	V _{GS} = -10V, I _D = -0.4A V _{GS} = -4.5V, I _D = -0.4A
Forward Transfer Admittance	Y _{fs}	—	1	—	S	V _{DS} = -10V, I _D = -0.4A
Diode Forward Voltage (Note 5)	V _{SD}	—	-0.8	-1.1	V	V _{GS} = 0V, I _S = -0.7A
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	—	160	—	pF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	120	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	50	—	pF	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{D(ON)}	—	10	—	ns	V _{DD} = -10V, I _D = -0.4A, V _{GS} = -5.0V, R _{GEN} = 50Ω
Turn-Off Delay Time	t _{D(OFF)}	—	25	—	ns	
Turn-On Rise Time	t _r	—	25	—	ns	
Turn-Off Fall Time	t _f	—	40	—	ns	

- Notes:
1. Device mounted on FR-4 PCB.
 2. No purposefully added lead.
 3. Pulse width ≤10μs, Duty Cycle ≤1%.
 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 5. Short duration pulse test used to minimize self-heating effect.



DMP3030SN

NEW PRODUCT

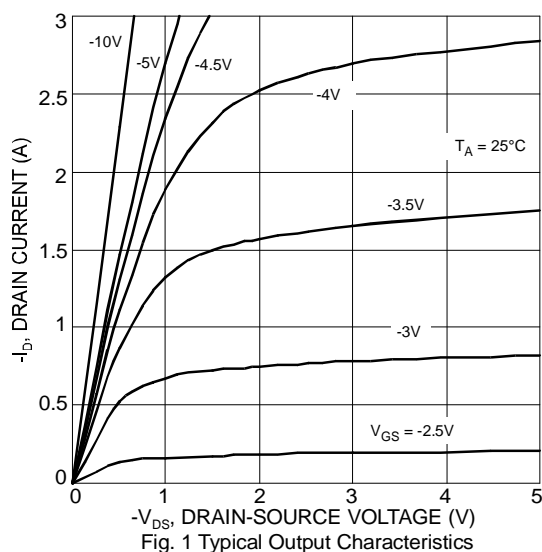


Fig. 1 Typical Output Characteristics

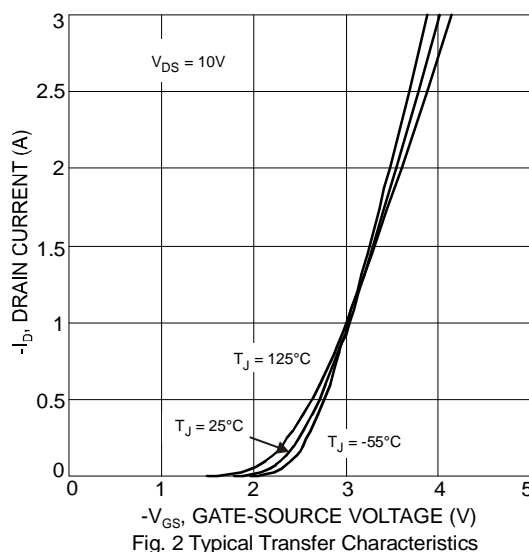


Fig. 2 Typical Transfer Characteristics

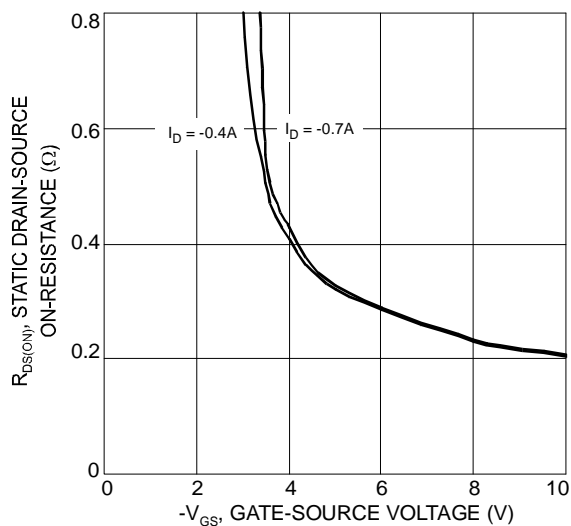


Fig. 3 On-Resistance vs. Gate Voltage

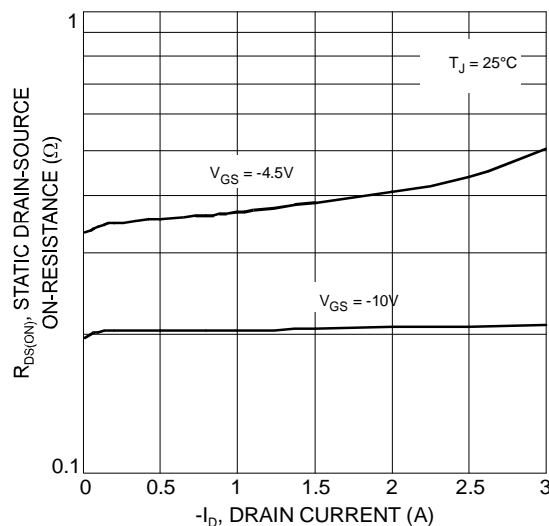


Fig. 4 On-Resistance vs. Drain Current

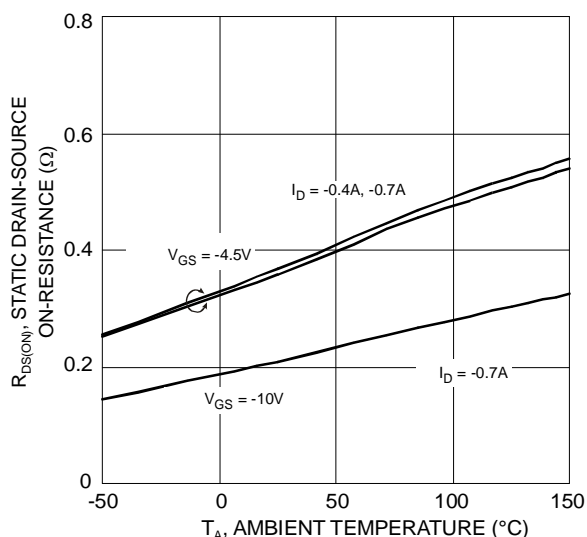


Fig. 5 On-Resistance Variation with Temperature

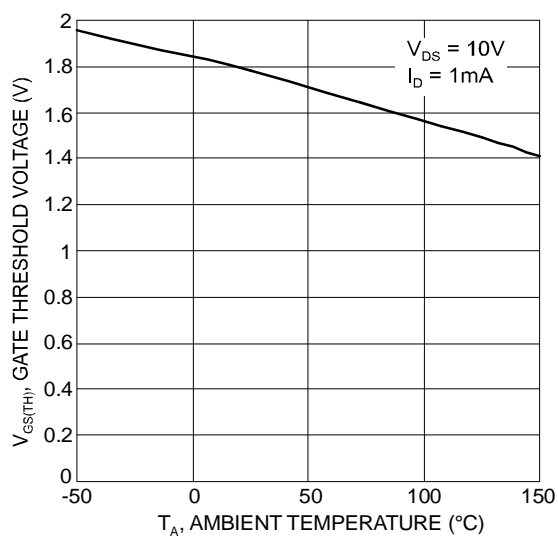


Fig. 6 Gate-Source Threshold Voltage with Temperature



DMP3030SN

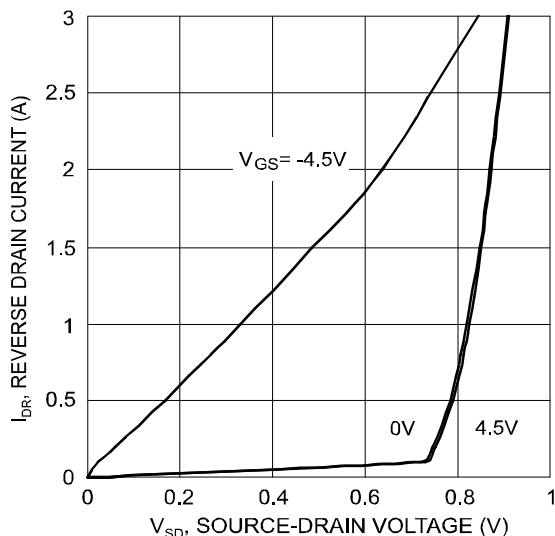


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

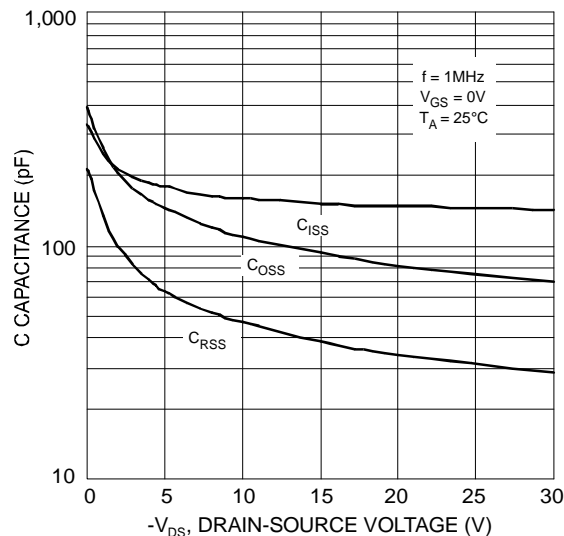


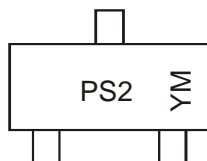
Fig. 8 Typical Total Capacitance

Ordering Information (Note 6)

Part Number	Case	Packaging
DMP3030SN-7	SC59	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



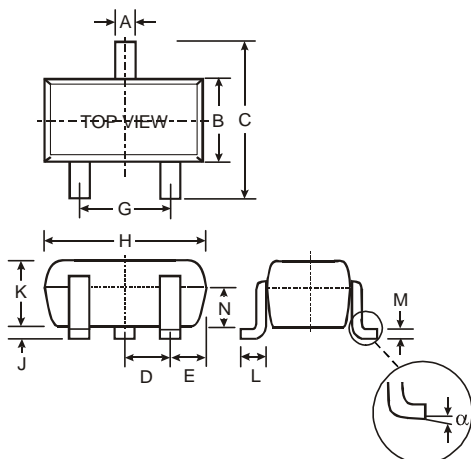
PS2 = Product Type Marking Code
YM = Date Code Marking
Y = Year ex: T = 2006
M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012
Code	T	U	V	W	X	Y	Z

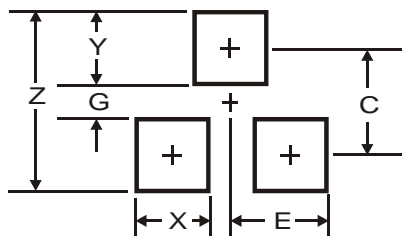
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions



SC59		
Dim	Min	Max
A	0.35	0.50
B	1.50	1.70
C	2.70	3.00
D	0.95	
E	—	
G	1.90	
H	2.90	3.10
J	0.013	0.10
K	1.00	1.30
L	0.35	0.55
M	0.10	0.20
N	0.70	0.80
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	4.0
G	1.2
X	0.9
Y	1.4
C	2.6
E	0.95

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